

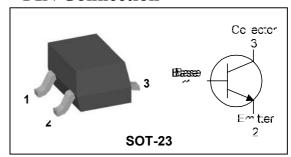


**NPN Silicon Transistor** 

## **Descriptions**

- General purpose application
- Switching application
- High voltage: V<sub>CEO</sub>=45V
- Complementary pair with KBC857

### **PIN Connection**



# **Ordering Information**

Type NO.	Marking	Package Code		
KBC847	<u>KK</u> <u> </u>	SOT-23		
	1 2 3	301-23		

① Device Code ② hFE Rank ③ Year&Week Code . Dalian

### Absolute maximum ratings

(Ta=25 C)

Characteristic	Symbol	Ratings	Unit	
Collector-Base voltage	$V_{CBO}$	50	V	
Collector-Emitter voltage	V <sub>CEO</sub> 45		V	
Emitter-base voltage	$V_{EBO}$	5	V	
Collector current	$I_{C}$	100	mA	
Collector dissipation	P <sub>C</sub>	200	mW	
Junction temperature	$T_{j}$	150	°C	
Storage temperature	$T_{stg}$	-55~150	°C	

#### **Electrical Characteristics**

(Ta=25 C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base breakdown voltage	BV <sub>CBO</sub>	I <sub>C</sub> =100uA, I <sub>E</sub> =0	50	-	-	V
Collector-Emitter breakdown voltage	BV <sub>CEO</sub>	$I_C=1$ mA, $I_B=0$	45	-	-	V
Emitter-Base breakdown voltage	BV <sub>EBO</sub>	BV <sub>EBO</sub> I <sub>E</sub> =10uA, I <sub>C</sub> =0		-	-	V
Base-Emitter turn on voltage	V <sub>BE(ON)</sub>	$V_{CE}=5V$ , $I_{C}=2mA$	0.55	-	0.7	V
Base-Emitter saturation voltage	$V_{BE(sat)}$	I <sub>C</sub> =100mA, I <sub>B</sub> =5mA	-	0.9	1.1	V
Collector-Emitter saturation voltage	$V_{CE(sat)}$	I <sub>C</sub> =100mA, I <sub>B</sub> =5mA	-	-	0.6	V
Collector-base cut-off current	$I_{CBO}$	V <sub>CB</sub> =35V, I <sub>E</sub> =0	-	-	15	nA
Collector-emitter cut-off current	$I_{CEO}$	V <sub>CE</sub> =30V, I <sub>B</sub> =0	-	-	1	uA
Emitter-base cut-off current	$I_{EBO}$	V <sub>EB</sub> =5V, I <sub>C</sub> =0	-	-	100	nA
DC current gain	h <sub>FE</sub> *	V <sub>CE</sub> =5V, I <sub>C</sub> =2mA	110	-	800	-
Transition frequency	f⊤	$V_{CE}$ =5V, $I_{C}$ =10mA f=100MHz	-	150	1	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB}=10V$ , $I_{E}=0$ , $f=1MHz$	-	-	4.5	pF
Noise figure	NF	$V_{CE}$ =5V, $I_{C}$ =200 $\mu$ A, $f$ =1KHz, $Rg$ =2K $\Omega$	-	-	10	dB

<sup>\*:</sup>  $h_{FE}$  rank / A: 110 ~ 220, B: 200 ~ 450, C: 420 ~ 800

#### **Electrical Characteristic Curves**

Fig. 1 P<sub>C</sub> -T<sub>a</sub>

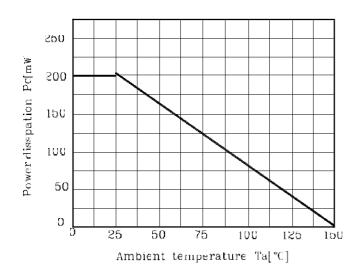


Fig. 2 I<sub>C</sub> -V<sub>BE</sub>

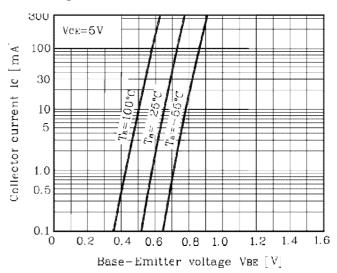


Fig. 3  $I_{\text{C}}$  -V  $_{\text{CE}}$ 

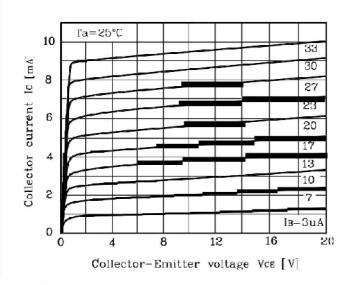


Fig. 4  $h_{FE}$ - $I_C$ 

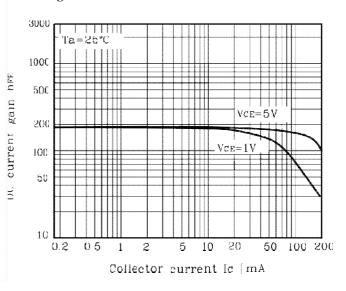
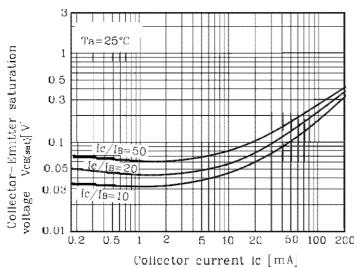
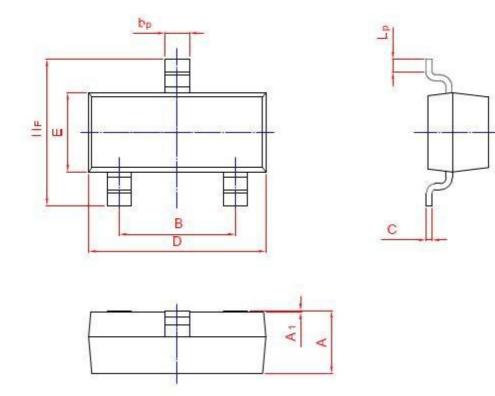


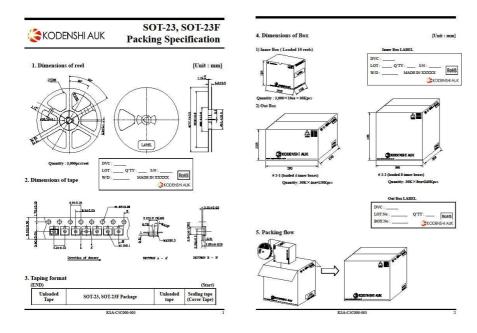
Fig. 5 V<sub>CE(sat)</sub> -I<sub>C</sub>



# **Outline Dimension**



UNIT	Α	В	bp	С	D	E	HE	A1	Lp
mm	1.40	2.04	0.50	0.19	3.10	1.65	3.00	0.100	0.50
	0.95	1.78	0.35	0.08	2.70	1.20	2.20	0.013	0.20



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